

# FET Input Analog Front End with ADC Driver

Data Sheet ADA4350

#### **FEATURES**

Low noise, low input bias current FET input amplifier Very low input bias current: ±0.25 pA typical at 25°C Low input voltage noise

92 nV/√Hz typical at 10 Hz at 5 V 5 nV/√Hz typical at 100 kHz at ±5 V Gain bandwidth product: 175 MHz Input capacitance

3 pF typical, differential mode

2 pF typical, common mode

Integrated gain switching

Sampling and feedback switch off leakage: ±0.5 pA typical Worst-case ton/toff times: 105 ns typical/65 ns typical Integrated analog-to-digital converter (ADC) driver

Differential mode and single-ended mode
Adjustable output common-mode voltage

-5 V to +3.8 V typical for ±5 V supply

Wide output voltage swing:  $\pm 4.8$  V minimum for  $\pm 5$  V supply Linear output current: 18 mA rms typical for  $\pm 5$  V supply

SPI or parallel switch control of all functions

Wide operating range: 3.3 V to 12 V

Quiescent current: 8.5 mA typical (±5 V full system)

#### **APPLICATIONS**

Current to voltage (I to V) conversions
Photodiode preamplifiers
Chemical analyzers
Mass spectrometry
Molecular spectroscopy
Laser/LED receivers
Data acquisition systems

#### **GENERAL DESCRIPTION**

The ADA4350 is an analog front end for photodetectors or other sensors whose output produces a current proportional to the sensed parameter or voltage input applications where the system requires the user to select between very precise gain levels to maximize the dynamic range.

The ADA4350 integrates a FET input amplifier, a switching network, and an ADC driver with all functions controllable via a serial peripheral interface (SPI) or parallel control logic into a single IC. The FET input amplifier has very low voltage noise and current noise making it an excellent choice to work with a wide range of photodetectors, sensors, or precision data acquisition systems.

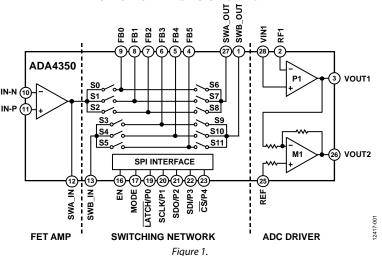
Its switching network allows the user individual selection of up to six different, externally configurable feedback networks; by using external components for the feedback network, the user can more easily match the system to their desired photodetector or sensor capacitance. This feature also allows the use of low thermal drift resistors, if required.

The design of the switches minimizes error sources so that they add virtually no error in the signal path. The output driver can be used in either single-ended or a differential mode and is ideal for driving the input of an ADC.

The ADA4350 can operate from a single +3.3 V supply or a dual  $\pm 5$  V supply, offering user flexibility when choosing the polarity of the detector. It is available in a Pb-free, 28-lead TSSOP package and is specified to operate over the -40°C to +85°C temperature range.

Multifunction pin names may be referenced by their relevant function only.

#### **FUNCTIONAL BLOCK DIAGRAM**



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#### **REVISION HISTORY**

4/15—Revision 0: Initial Version

## SPECIFICATIONS ±5 V FULL SYSTEM

 $T_{\text{A}}$  = 25°C, +V  $_{\text{S}}$  = +5 V, -V  $_{\text{S}}$  = -5 V, RL = 1 k $\Omega$  differential, unless otherwise specified.

Table 1.

| Parameter                             | Test Conditions/Comments   | Min | Тур          | Max | Unit   |
|---------------------------------------|--|-----|--------------|-----|--------|
| DYNAMIC PERFORMANCE                   |  |     |              |     |        |
| –3 dB Bandwidth                       | $G = -5$ , $V_{OUT} = 200 \text{ mV p-p}$                              |     | 20           |     | MHz    |
|                                       | $G = -5$ , $V_{OUT} = 2 V p-p$   |     | 12           |     | MHz    |
| Slew Rate                             | V <sub>OUT</sub> = 2 V step, 10% to 90%                                |     | 60           |     | V/µs   |
| HARMONIC PERFORMANCE                  |  |     |              |     |        |
| Harmonic Distortion (HD2/HD3)         | $G = -5$ , $f_C = 100 \text{ kHz}$                                     |     | -95/-104     |     | dBc    |
|                                       | $G = -5$ , $f_C = 1$ MHz   |     | -77/-78      |     | dBc    |
| DC PERFORMANCE                        |  |     |              |     |        |
| Input Bias Current                    | At 25°C  |     | ±0.25        | ±1  | pА     |
|                                       | At 85°C  |     | ±8           | ±25 | рΑ     |
| INPUT CHARACTERISTICS                 |  |     |              |     |        |
| Input Resistance                      | Common mode  |     | 100          |     | GΩ     |
| Input Capacitance                     | Common mode  |     | 2            |     | pF     |
|                                       | Differential mode  |     | 3            |     | рF     |
| Input Common-Mode Voltage Range       | Common-mode rejection ratio (CMRR) > 80 dB                             |     | -4.5 to +3.8 |     | V      |
|                                       | CMRR > 68 dB   |     | -5 to +3.9   |     | V      |
| Common-Mode Rejection                 | $V_{CM} = \pm 3.0 \text{ V}$   | 92  | 104          |     | dB     |
| OUTPUT CHARACTERISTICS                |  |     |              |     |        |
| Linear Output Current                 | $V_{OUT} = 4 \text{ V p-p}$ , 60 dB spurious-free dynamic range (SFDR) |     | 18           |     | mA rms |
| Short-Circuit Current                 | Sinking/sourcing   |     | 43/76        |     | mA     |
| Settling Time to 0.1%                 | $G = -5$ , $V_{OUT} = 2 V$ step  |     | 100          |     | ns     |
| POWER SUPPLY                          |  |     |              |     |        |
| Operating Range                       |  | 3.3 |              | 12  | V      |
| Quiescent Current                     | Enabled  |     | 8.5          | 10  | mA     |
|                                       | M1 disabled (see Figure 1)   |     | 7            |     | mA     |
|                                       | All disabled   |     | 2            |     | μΑ     |
| Positive Power Supply Rejection Ratio |  |     | 90           |     | dB     |
| Negative Power Supply Rejection Ratio |  |     | 85           |     | dB     |

#### ±5 V FET INPUT AMPLIFIER

 $T_A = 25$ °C,  $+V_S = +5$  V,  $-V_S = -5$  V,  $R_L = 1$  k $\Omega$ , unless otherwise specified.

Table 2.

| Parameter                             | Test Conditions/Comments   | Min          | Тур            | Max  | Unit   |
|---------------------------------------|--|--------------|----------------|------|--------|
| DYNAMIC PERFORMANCE                   |  |              |                |      |        |
| –3 dB Bandwidth                       | $G = -5$ , $V_{OUT} = 100 \text{ mV p-p}$                            |              | 26             |      | MHz    |
|                                       | $G = -5$ , $V_{OUT} = 2 V p-p$                                       |              | 24             |      | MHz    |
| Gain Bandwidth Product                |  |              | 175            |      | MHz    |
| Slew Rate                             | V <sub>OUT</sub> = 2 V step, 10% to 90%                              |              | 100            |      | V/µs   |
| Settling Time to 0.1%                 | $G = -5$ , $V_{OUT} = 2 V$ step                                      |              | 28             |      | ns     |
| NOISE/HARMONIC PERFORMANCE            |  |              |                |      |        |
| Harmonic Distortion (HD2/HD3)         | $f = 100 \text{ kHz}, V_{OUT} = 2 \text{ V p-p}, G = -5$             |              | -106/-114      |      | dBc    |
|                                       | $f = 1 \text{ MHz}, V_{OUT} = 2 \text{ V p-p}, G = -5$               |              | -83/-93        |      | dBc    |
| Input Voltage Noise                   | f = 10 Hz  |              | 85             |      | nV/√Hz |
|                                       | f = 100 kHz  |              | 5              |      | nV/√Hz |
| DC PERFORMANCE                        |  |              |                |      |        |
| Input Offset Voltage                  |  |              | 15             | 80   | μV     |
| Input Offset Voltage Drift            | From -40°C to +85°C  |              | 0.1            | 1.6  | μV/°C  |
|                                       | From 25°C to 85°C  |              | 0.1            | 1.0  | μV/°C  |
| Input Bias Current                    | At 25°C  |              | ±0.25          | ±1   | рΑ     |
|                                       | At 85°C  |              | ±8             | ±25  | pА     |
| Input Bias Offset Current             | At 25°C  |              | ±0.1           | ±0.8 | рА     |
|                                       | At 85°C  |              | ±0.5           |      | рА     |
| Open-Loop Gain                        | $V_{OUT} = \pm 2 V$  | 106          | 115            |      | dB     |
| INPUT CHARACTERISTICS                 |  |              |                |      |        |
| Input Resistance                      | Common mode  |              | 100            |      | GΩ     |
| Input Capacitance                     | Common mode  |              | 2              |      | pF     |
|                                       | Differential mode  |              | 3              |      | pF     |
| Input Common-Mode Voltage Range       | CMRR > 80 dB   |              | -4.5 to +3.8   |      | V      |
|                                       | CMRR > 68 dB   |              | -5 to +3.9     |      | ٧      |
| Common-Mode Rejection Ratio           | $V_{CM} = \pm 3 V$   | 92           | 115            |      | V      |
| OUTPUT CHARACTERISTICS                |  |              |                |      |        |
| Output Overdrive Recovery Time        | $V_{OUT} = V_S \pm 10\%$   |              | 60             |      | ns     |
| Output Voltage Swing                  | $G = +21$ , $R_F = 1 \text{ k}\Omega$ , $R_L$ open measured at FBx   | -3.6 to +3.9 | -4.05 to +4.07 |      | V      |
|                                       | $G = +21$ , $R_F = 100 \text{ k}\Omega$ , $R_L$ open measured at FBx | -4.7 to +4.8 | -4.9 to +4.86  |      | ٧      |
| Linear Output Current                 | $V_{OUT} = 2 V p-p, 60 dB SFDR$                                      |              | 18             |      | mA rms |
| Short-Circuit Current                 | Sinking/sourcing   |              | 41/45          |      | mA     |
| POWER SUPPLY                          | _  |              |                |      |        |
| Operating Range                       |  | 3.3          |                | 12   | V      |
| Positive Power Supply Rejection Ratio |  | 90           | 109            |      | dB     |
| Negative Power Supply Rejection Ratio |  | 90           | 109            |      | dB     |

#### ±5 V INTERNAL SWITCHING NETWORK AND DIGITAL PINS

 $T_A = 25$ °C,  $+V_S = +5$  V,  $-V_S = -5$  V, unless otherwise specified. See Figure 1 for feedback and sampling switches notation.

Table 3.

| Parameter   | Symbol                | Test Conditions/Comments              | Min | Тур        | Max  | Unit |
|---|-----------------------|---------------------------------------|-----|------------|------|------|
| FEEDBACK/SAMPLE ANALOG SWITCH                       |                       |                                       |     |            |      |      |
| Analog Signal Range                                 |                       |                                       | -5  |            | +5   | V    |
| Switch On-Resistance                                |                       |                                       |     |            |      |      |
| Feedback  | R <sub>ON, FB</sub>   | For S0 to S2, $V_{CM} = 0 V$          |     | 149        | 196  | Ω    |
|   |                       | T <sub>A</sub> = 85°C                 |     | 195        |      | Ω    |
|   |                       | For S3 to S5, $V_{CM} = 0 V$          |     | 149        | 196  | Ω    |
|   |                       | T <sub>A</sub> = 85°C                 |     | 195        |      | Ω    |
| Sampling  | Ron, s                | For S6 to S8, $V_{CM} = 0 V$          |     | 297        | 356  | Ω    |
| , ,   |                       | T <sub>A</sub> = 85°C                 |     | 390        |      | Ω    |
|   |                       | For S9 to S11, $V_{CM} = 0 \text{ V}$ |     | 297        | 356  | Ω    |
|   |                       | T <sub>A</sub> = 85°C                 |     | 388        |      | Ω    |
| On-Resistance Match Between Channels                |                       |                                       |     |            |      |      |
| Feedback Resistance                                 | ΔR <sub>ON, FB</sub>  | $V_{CM} = 0 V$                        |     | 2          | 15   | Ω    |
| Sampling Resistance                                 | ΔR <sub>ON, S</sub>   | $V_{CM} = 0 V$                        |     | 2          | 14   | Ω    |
| SWITCH LEAKAGE CURRENTS                             |                       |                                       |     |            |      |      |
| Sampling and Feedback Switch Off Leakage            | I <sub>S (OFF)</sub>  |                                       |     | ±0.5       | ±1.7 | рА   |
| p 3   |                       | T <sub>A</sub> = 85°C                 |     | ±40        | ±120 | рA   |
| DYNAMIC CHARACTERISTICS                             |                       |                                       |     |            |      | Ė    |
| Power-On Time                                       | ton                   | DVDD = 5 V                            |     | 76         |      | ns   |
|   |                       | DVDD = 3.3 V                          |     | 80         |      | ns   |
| Power-Off Time                                      | toff                  | DVDD = 5 V                            |     | 86         |      | ns   |
|   |                       | DVDD = 3.3 V                          |     | 90         |      | ns   |
| Off Isolation                                       |                       | $R_L = 50 \Omega$ , $f = 1 MHz$       |     |            |      |      |
| Feedback Switches                                   |                       |                                       |     | -92        |      | dB   |
| Sampling Switches                                   |                       |                                       |     | -118       |      | dB   |
| Channel-to-Channel Crosstalk                        |                       | $R_L = 50 \Omega$ , $f = 1 MHz$       |     | -86        |      | dB   |
| Worst-Case Switch Feedback Capacitance (Switch Off) | C <sub>FB</sub> (OFF) |                                       |     | 0.1        |      | рF   |
| THRESHOLD VOLTAGES FOR DIGITAL INPUT PINS           |                       | EN, MODE, DGND, LATCH/P0,             |     |            |      | -    |
|   |                       | SCLK/P1, SDO/P2, SDI/P3, CS/P41       |     |            |      |      |
| Input High Voltage                                  | V <sub>IH</sub>       | DVDD = 5 V                            | 2.0 |            |      | V    |
|   |                       | DVDD = 3.3 V                          | 1.5 |            |      | V    |
| Input Low Voltage                                   | VII                   | DVDD = 5 V                            |     |            | 1.4  | V    |
| put 2011 rolluge                                    | 1                     | DVDD = 3.3 V                          |     |            | 1.0  | V    |
| DIGITAL SUPPLIES                                    |                       | DVDD, DGND                            |     |            |      |      |
| Digital Supply Range                                |                       |                                       |     | 3.3 to 5.5 |      | V    |
| Ouiescent Current                                   |                       | <br>  Enabled                         |     | 50         |      | μA   |
| 2   |                       | Disabled                              |     | 0.6        |      | μΑ   |
|   | I                     | 2.535.63                              |     | ≥3.3       |      | V    |

<sup>&</sup>lt;sup>1</sup> When referring to a single function of a multifunction pin, only the portion of the pin name that is relevant to the specification is listed. For full pin names of multifunction pins, refer to the Pin Configuration and Function Descriptions section.

#### ±5 V ADC DRIVER

 $T_A = 25$ °C,  $+V_S = +5$  V,  $-V_S = -5$  V, unless otherwise specified. See Figure 1 for the P1 and M1 amplifiers.  $R_L = 1$  k $\Omega$  when differential, and  $R_L = 500$   $\Omega$  when single-ended.

Table 4.

| Parameter                              | Test Conditions/Comments <sup>1</sup>   | Min  | Тур        | Max         | Unit    |
|--|---|------|------------|-------------|---------|
| DYNAMIC PERFORMANCE                    |   |      |            |             |         |
| –3 dB Bandwidth                        | When used differentially, $V_{OUT} = 0.1 \text{ V p-p}$                         |      | 38         |             | MHz     |
|  | When used differentially, $V_{OUT} = 2.0 \text{ V p-p}$                         |      | 16         |             | MHz     |
|  | When P1 is used, $V_{OUT} = 50 \text{ mV p-p}$                                  |      | 55         |             | MHz     |
|  | When P1 is used, $V_{OUT} = 1.0 \text{ V p-p}$                                  |      | 17         |             | MHz     |
|  | When M1 is used, $V_{OUT} = 50 \text{ mV p-p}$                                  |      | 45         |             | MHz     |
|  | When M1 is used, $V_{OUT} = 1.0 \text{ V p-p}$                                  |      | 21         |             | MHz     |
| Overdrive Recovery Time                | Positive (+) recovery/negative (–) recovery for P1                              |      | 200/180    |             | ns      |
| ·                                      | Positive (+) recovery/negative (–) recovery for M1                              |      | 100/100    |             | ns      |
| Slew Rate                              | When differentially used, $V_{OUT} = 2 \text{ V step}$                          |      | 57         |             | V/µs    |
|  | When P1 or M1 is single-ended, $V_{OUT} = 1 \text{ V step}$                     |      | 30         |             | V/µs    |
| Settling Time 0.1%                     | When used differentially, $V_{OUT} = 2 \text{ V step}$                          |      | 95         |             | ns      |
| -                                      | When P1 is used, $V_{OUT} = 1 \text{ V step}$                                   |      | 80         |             | ns      |
|  | When M1 is used, $V_{OUT} = 1 \text{ V step}$                                   |      | 80         |             | ns      |
| NOISE/DISTORTION PERFORMANCE           | ·   |      |            |             |         |
| Harmonic Distortion (HD2/HD3)          | When used differentially, $f_C = 100 \text{ kHz}$ , $V_{OUT} = 4 \text{ V p-p}$ |      | -105/-109  |             | dBc     |
| ,                                      | When used differentially, $f_c = 1$ MHz, $V_{OUT} = 4$ V p-p                    |      | -75/-73    |             | dBc     |
|  | When P1 is used, $f_C = 100 \text{ kHz}$ , $V_{OUT} = 2 \text{ V p-p}$          |      | -112/-108  |             | dBc     |
|  | When P1 is used, $f_C = 1$ MHz, $V_{OUT} = 2$ V p-p                             |      | -75/-73    |             | dBc     |
|  | When M1 is used, $f_C = 100 \text{ kHz}$ , $V_{OUT} = 2 \text{ V p-p}$          |      | -98/-103   |             | dBc     |
|  | When M1 is used, $f_C = 1$ MHz, $V_{OUT} = 2$ V p-p                             |      | -70/-69    |             | dBc     |
| Referred to Input (RTI) Voltage Noise  | For P1, f = 10 Hz   |      | 55         |             | nV/√Hz  |
| , , , , , , , , , , , , , , , , , , ,  | For P1, f = 100 kHz   |      | 5          |             | nV/√Hz  |
| Referred to Output (RTO) Voltage Noise | For P1 and M1, f = 10 Hz, measured at VOUT2                                     |      | 95         |             | nV/√Hz  |
|  | For P1 and M1, f = 100 kHz, measured at VOUT2                                   |      | 16         |             | nV/√Hz  |
| Input Current Noise                    | f = 100 kHz, referred to P1   |      | 1.1        |             | pA/√Hz  |
| DC PERFORMANCE                         |   |      |            |             | p. 4 V  |
| Output Offset Voltage                  | Differential  |      | 0.125      | 0.5         | mV      |
| Output Offset Voltage Drift            | Differential  |      | 0.7        | 13          | μV/°C   |
| Input Offset Voltage                   | Single-ended, P1 only   |      | 50         | 180         | μV      |
| pat oset tomage                        | Single-ended, M1 only   |      | 40         | 180         | μV      |
| Input Offset Voltage Drift             | Single-ended, P1 only   |      | 0.2        | 4.75        | μV/°C   |
| input onset voltage bint               | Single-ended, M1 only   |      | 0.4        | 3.6         | μV/°C   |
| Input Bias Current                     | P1 only at VIN1 pin   |      | 60         | 220         | nA      |
| input bias current                     | P1 only at RF1 pin  |      | 60         | 325         | nA      |
|  | M1 at REF pin   |      | 60         | 200         | nA      |
| Input Offset Current                   | P1 only   |      | 60         | 260         | nA      |
| Open-Loop Gain                         | P1 only, $V_{OUT} = \pm 2 V$  | 102  | 112        | 200         | dB      |
| Gain                                   | M1 only   | 1.99 | 1.9996     | 2.01        | V/V     |
| Gain Error                             | in only   | -0.5 | 1.9990     | +0.5        | %       |
| Gain Error<br>Gain Error Drift         |   | -0.5 | 0.6        | +0.5<br>1.9 | ppm/°C  |
| INPUT CHARACTERISTICS                  |   |      | 0.0        | 1.7         | ррпі/ С |
| Input Resistance                       | VIN1 and REF  |      | 200        |             | ΜΩ      |
| •                                      |   |      | 200        |             |         |
| Input Common Mode Voltage Range        | VIN1 and REF  |      | 1.4        |             | pF      |
| Input Common-Mode Voltage Range        | For D1 V 12 OV  | 02   | -5 to +3.8 |             | V       |
| Common-Mode Rejection Ratio            | For P1, $V_{CM} = \pm 3.0 \text{ V}$  | 82   | 100        |             | dB      |

| Parameter                             | Test Conditions/Comments <sup>1</sup>  | Min   | Тур        | Max | Unit   |
|---------------------------------------|--|-------|------------|-----|--------|
| OUTPUT CHARACTERISTICS                |  |       |            |     |        |
| Output Voltage Swing                  | $R_L = no load, single-ended$  | ±4.8  | ±4.83      |     | V      |
|                                       | $R_L = 500 \Omega$ , single-ended  | ±4.55 | ±4.6       |     | V      |
| Output Common-Mode Voltage Range      |  |       | -5 to +3.8 |     | V      |
| Linear Output Current                 | P1 or M1, V <sub>OUT</sub> = 2 V p-p, 60 dB SFDR   |       | 18         |     | mA rms |
|                                       | Differential output, V <sub>OUT</sub> = 4 V p-p, 60 dB SFDR  |       | 18         |     | mA rms |
| Short Circuit Current                 | P1 or M1, sinking/sourcing   |       | 43/76      |     | mA     |
| Capacitive Load Drive                 | When used differentially at each VOUTx, 30% overshoot, $V_{\text{OUT}} = 200 \text{mV} \text{p-p}$ |       | 33         |     | pF     |
|                                       | When P1/M1 is used, 30% overshoot, $V_{OUT} = 100 \text{ mV p-p}$                                  |       | 47         |     | рF     |
| POWER SUPPLY                          |  |       |            |     |        |
| Operating Range                       |  | 3.3   |            | 12  | V      |
| Positive Power Supply Rejection Ratio | For P1   | 90    | 106        |     | dB     |
|                                       | For M1   | 86    | 100        |     | dB     |
| Negative Power Supply Rejection Ratio | For P1   | 80    | 100        |     | dB     |
|                                       | For M1   | 78    | 90         |     | dB     |

 $<sup>^{\</sup>rm 1}\,{\rm P1}$  and M1 within this table refer to the amplifiers shown in Figure 1.

#### **5 V FULL SYSTEM**

 $T_{\text{A}}$  = 25°C, +V  $_{\text{S}}$  = 5 V, -V  $_{\text{S}}$  = 0 V,  $R_{\text{F}}$  = 1  $k\Omega$  differential, unless otherwise specified.

Table 5.

| Parameter                             | Test Conditions/Comments                             | Min | Тур        | Max  | Unit   |
|---------------------------------------|--|-----|------------|------|--------|
| DYNAMIC PERFORMANCE                   |  |     |            |      |        |
| −3 dB Bandwidth                       | $G = -5$ , $V_{OUT} = 200 \text{ mV p-p}$            |     | 15         |      | MHz    |
|                                       | $G = -5$ , $V_{OUT} = 1 \text{ V p-p}$               |     | 14         |      | MHz    |
| Slew Rate                             | $V_{OUT} = 2 \text{ V step, } 10\% \text{ to } 90\%$ |     | 30         |      | V/µs   |
| HARMONIC PERFORMANCE                  |  |     |            |      |        |
| Harmonic Distortion (HD2/HD3)         | $G = -5$ , $f_C = 100 \text{ kHz}$                   |     | -85/-94    |      | dBc    |
|                                       | $G = -5$ , $f_C = 1$ MHz                             |     | -66/-75    |      | dBc    |
| Input Voltage Noise                   | f = 10 Hz  |     | 92         |      | nV/√Hz |
|                                       | f = 100 kHz  |     | 4.4        |      | nV/√Hz |
| DC PERFORMANCE                        |  |     |            |      |        |
| Input Bias Current                    | At 25°C  |     | ±0.35      | ±1.6 | pА     |
| ·                                     | At 85°C  |     | ±8.5       | ±30  | pA     |
| INPUT CHARACTERISTICS                 |  |     |            |      |        |
| Input Resistance                      | Common mode  |     | 100        |      | GΩ     |
| Input Capacitance                     | Common mode  |     | 2          |      | pF     |
|                                       | Differential mode                                    |     | 3          |      | pF     |
| Input Common-Mode Voltage Range       | CMRR > 80 dB   |     | 0.5 to 3.8 |      | V      |
|                                       | CMRR > 68 dB   |     | 0 to 3.9   |      | V      |
| Common-Mode Rejection                 | $V_{CM} = \pm 0.5 V$                                 | 88  | 94         |      | dB     |
| OUTPUT CHARACTERISTICS                |  |     |            |      |        |
| Linear Output Current                 | $V_{OUT} = 1 \text{ V p-p, } 60 \text{ dB SFDR}$     |     | 9          |      | mA rms |
| Short-Circuit Current                 | Sinking/sourcing, $R_L < 1 \Omega$                   |     | 41/63      |      | mA     |
| Settling Time to 0.1%                 | $G = -5$ , $V_{OUT} = 2 V$ step                      |     | 130        |      | ns     |
| POWER SUPPLY                          |  |     |            |      |        |
| Operating Range                       |  | 3.3 |            | 12   | V      |
| Quiescent Current                     | Enabled  |     | 8          | 9    | mA     |
|                                       | M1 disabled (see Figure 1)                           |     | 6.5        |      | mA     |
|                                       | All disabled   |     | 2          |      | μΑ     |
| Positive Power Supply Rejection Ratio |  |     | 86         |      | dB     |
| Negative Power Supply Rejection Ratio |  |     | 80         |      | dB     |

#### **5 V FET INPUT AMPLIFIER**

 $T_A$  = 25°C, +V\_S = 5 V, -V\_S = 0 V,  $R_L$  = 1 k $\Omega$ , unless otherwise specified.

#### Table 6.

| Parameter                             | Test Conditions/Comments   | Min          | Тур          | Max   | Unit   |
|---------------------------------------|--|--------------|--------------|-------|--------|
| DYNAMIC PERFORMANCE                   |  |              |              |       |        |
| −3 dB Bandwidth                       | $G = -5$ , $V_{OUT} = 100 \text{ mV p-p}$                            |              | 25           |       | MHz    |
|                                       | $G = -5$ , $V_{OUT} = 1 V p-p$                                       |              | 24           |       | MHz    |
| Gain Bandwidth Product                |  |              | 175          |       | MHz    |
| Slew Rate                             | V <sub>OUT</sub> = 2 V step, 10% to 90%                              |              | 56           |       | V/µs   |
| Settling Time to 0.1%                 | $G = -5$ , $V_{OUT} = 2 V$ step                                      |              | 60           |       | ns     |
| NOISE/HARMONIC PERFORMANCE            |  |              |              |       |        |
| Harmonic Distortion (HD2/HD3)         | $f = 100 \text{ kHz}, V_{OUT} = 1 \text{ V p-p, G} = -5$             |              | -113/-117    |       | dBc    |
|                                       | $f = 1 \text{ MHz}, V_{OUT} = 1 \text{ V p-p, G} = -5$               |              | -82/-83      |       | dBc    |
| Input Voltage Noise                   | f = 10 Hz  |              | 92           |       | nV/√Hz |
|                                       | f = 100 kHz  |              | 4.4          |       | nV/√Hz |
| DC PERFORMANCE                        |  |              |              |       |        |
| Input Offset Voltage                  |  |              | 25           | 80    | μV     |
| Input Offset Voltage Drift            | From -40°C to +85°C  |              | 0.1          | 1.5   | μV/°C  |
|                                       | From 25°C to 85°C  |              | 0.05         | 1     | μV/°C  |
| Input Bias Current                    | At 25°C  |              | ±0.35        | ±1.6  | pA     |
| ·                                     | At 85°C  |              | ±8.5         | ±30   | pA     |
| Input Bias Offset Current             | At 25°C  |              | ±0.25        | ±1.25 | pA     |
| •                                     | At 85°C  |              | ±0.4         |       | pА     |
| Open-Loop Gain                        | $V_{OUT} = 1.5 \text{ V to } 3.5 \text{ V}$                          | 98           | 102          |       | dB     |
| INPUT CHARACTERISTICS                 |  |              |              |       |        |
| Input Resistance                      | Common mode  |              | 100          |       | GΩ     |
| Input Capacitance                     | Common mode  |              | 2            |       | pF     |
|                                       | Differential mode  |              | 3            |       | pF     |
| Input Common-Mode Voltage Range       | CMRR > 80 dB   |              | 0.5 to 3.8   |       | V      |
|                                       | CMRR > 68 dB   |              | 0 to 3.9     |       | V      |
| Common-Mode Rejection Ratio           | $V_{CM} = \pm 0.5V$  | 88           | 94           |       | dB     |
| OUTPUT CHARACTERISTICS                |  |              |              |       |        |
| Output Overdrive Recovery Time        | $V_{OUT} = V_S \pm 10\%$ , positive/negative                         |              | 60/50        |       | ns     |
| Output Voltage Swing                  | $G = +21$ , $R_F = 1$ k $\Omega$ , $R_L$ open measured at FBx        | 1.15 to 3.46 | 0.86 to 3.66 |       | V      |
|                                       | $G = +21$ , $R_F = 100 \text{ k}\Omega$ , $R_L$ open measured at FBx | 0.27 to 4.80 | 0.08 to 4.87 |       | V      |
| Linear Output Current                 | V <sub>OUT</sub> = 1 V p-p, 60 dB SFDR                               |              | 10           |       | mA rms |
| Short-Circuit Current                 | Sinking/sourcing   |              | 32/38        |       | mA     |
| POWER SUPPLY                          |  |              |              |       |        |
| Operating Range                       |  | 3.3          |              | 12    | V      |
| Positive Power Supply Rejection Ratio |  | 90           | 100          |       | dB     |
| Negative Power Supply Rejection Ratio |  | 86           | 100          |       | dB     |

#### **5 V INTERNAL SWITCHING NETWORK AND DIGITAL PINS**

 $T_A = 25$ °C,  $+V_S = 5$  V,  $-V_S = 0$  V, unless otherwise specified. See Figure 1 for sampling and feedback switches position.

Table 7.

| Parameter   | Symbol                     | Test Conditions/Comments   | Min | Тур        | Max  | Unit |
|---|----------------------------|--|-----|------------|------|------|
| FEEDBACK/SAMPLE ANALOG SWITCH                       |                            |  |     |            |      |      |
| Analog Signal Range                                 |                            |  | 0   |            | 5    | V    |
| Switch On Resistance                                |                            |  |     |            |      |      |
| Feedback  | Ron, fb                    | S0 to S2, $V_{CM} = 2.5 \text{ V}$                                       |     | 308        | 390  | Ω    |
|   |                            | $T_A = 85$ °C  |     | 382        |      | Ω    |
|   |                            | S3 to S5, $V_{CM} = 2.5 \text{ V}$                                       |     | 308        | 390  | Ω    |
|   |                            | $T_A = 85$ °C  |     | 384        |      | Ω    |
| Sampling  | Ron, s                     | S6 to S8, $V_{CM} = 2.5 \text{ V}$                                       |     | 610        | 770  | Ω    |
|   |                            | $T_A = 85$ °C  |     | 762        |      | Ω    |
|   |                            | S9 to S11, $V_{CM} = 2.5 \text{ V}$                                      |     | 612        | 770  | Ω    |
|   |                            | $T_A = 85$ °C  |     | 764        |      | Ω    |
| On-Resistance Match Between Channels                |                            |  |     |            |      |      |
| Feedback Resistance                                 | $\Delta R_{\text{ON, FB}}$ | $V_{CM} = 2.5 V$   |     | 3          | 21   | Ω    |
| Sampling Resistance                                 | $\Delta R_{\text{ON, S}}$  | $V_{CM} = 2.5 \text{ V}$   |     | 3          | 23   | Ω    |
| SWITCH LEAKAGE CURRENTS                             |                            |  |     |            |      |      |
| Sampling and Feedback Switch Off Leakage            | Is (OFF)                   |  |     | ±0.4       | ±1.2 | рΑ   |
|   |                            | $T_A = 85$ °C  |     | ±30        | ±80  | рΑ   |
| DYNAMIC CHARACTERISTICS                             |                            |  |     |            |      |      |
| Power-On Time                                       | ton                        | DVDD = 3.3 V   |     | 105        |      | ns   |
| Power-Off Time                                      | toff                       | DVDD = 3.3 V   |     | 65         |      | ns   |
| Off Isolation                                       |                            | $R_L = 50 \Omega$ , $f = 1 MHz$  |     |            |      |      |
| Feedback Switches                                   |                            |  |     | -93        |      | dB   |
| Sampling Switches                                   |                            |  |     | -116       |      | dB   |
| Channel-to-Channel Crosstalk                        |                            | $R_L = 50 \Omega$ , $f = 1 MHz$  |     | -83        |      | dB   |
| Worst-Case Switch Feedback Capacitance (Switch Off) | C <sub>FB</sub> (OFF)      |  |     | 0.1        |      | рF   |
| THRESHOLD VOLTAGES FOR DIGITAL INPUT PINS           |                            | EN, MODE, DGND, LATCH/P0,<br>SCLK/P1, SDO/P2, SDI/P3, CS/P4 <sup>1</sup> |     |            |      |      |
| Input High Voltage                                  | V <sub>IH</sub>            | DVDD = 5 V   | 2.0 |            |      | V    |
|   |                            | DVDD = 3.3 V   | 1.5 |            |      | V    |
| Input Low Voltage                                   | V <sub>IL</sub>            | DVDD = 5 V   |     |            | 1.4  | V    |
| ,   |                            | DVDD = 3.3 V   |     |            | 1.0  | V    |
| DIGITAL SUPPLIES                                    |                            | DVDD, DGND   |     |            |      |      |
| Digital Supply Range                                |                            |  |     | 3.3 to 5.5 |      | V    |
| Quiescent Current                                   |                            | Enabled  |     | 50         |      | μΑ   |
|   |                            | Disabled   |     | 0.6        |      | μA   |
| +V <sub>s</sub> to DGND Head Room                   |                            |  |     | ≥3.3       |      | V    |

<sup>&</sup>lt;sup>1</sup> When referring to a single function of a multifunction pin, only the portion of the pin name that is relevant to the specification is listed. For full pin names of multifunction pins, refer to the Pin Configuration and Function Descriptions section.

#### **5 V ADC DRIVER**

 $T_A = 25$ °C,  $+V_S = 5$  V,  $-V_S = 0$  V, unless otherwise specified. See Figure 1 for the P1 and M1 amplifiers,  $R_L = 1$  k $\Omega$  when differential, and  $R_L = 500$   $\Omega$  when single-ended.

Table 8.

| Parameter                              | Test Conditions/Comments <sup>1</sup>   | Min  | Тур       | Max  | Unit  |
|--|---|------|-----------|------|-------|
| DYNAMIC PERFORMANCE                    |   |      |           |      |       |
| –3 dB Bandwidth                        | When used differentially, $V_{OUT} = 0.1 \text{ V p-p}$                         |      | 33        |      | MHz   |
|  | When used differentially, $V_{OUT} = 2.0 \text{ V p-p}$                         |      | 16        |      | MHz   |
|  | When P1 is used, $V_{OUT} = 50 \text{ mV p-p}$                                  |      | 47        |      | MHz   |
|  | When P1 is used, $V_{OUT} = 1.0 \text{ V p-p}$                                  |      | 16        |      | MHz   |
|  | When M1 is used, $V_{OUT} = 50 \text{ mV p-p}$                                  |      | 37        |      | MHz   |
|  | When M1 is used, $V_{OUT} = 1.0 \text{ V p-p}$                                  |      | 18        |      | MHz   |
| Overdrive Recovery Time                | For P1, positive (+) recovery/<br>negative (–) recovery                         |      | 200/200   |      | ns    |
|  | For M1, positive (+) recovery/<br>negative (–) recovery                         |      | 140/120   |      | ns    |
| Slew Rate                              | When differentially used, $V_{OUT} = 2 \text{ V step}$                          |      | 37        |      | V/µs  |
|  | When P1 or M1 is single-ended, $V_{OUT} = 1 \text{ V step}$                     |      | 20        |      | V/µs  |
| Settling Time 0.1%                     | When used differentially, $V_{OUT} = 2 \text{ V step}$                          |      | 75        |      | ns    |
|  | When P1 is used, $V_{OUT} = 1 \text{ V step}$                                   |      | 60        |      | ns    |
|  | When M1 is used, $V_{OUT} = 1 \text{ V step}$                                   |      | 60        |      | ns    |
| NOISE/DISTORTION PERFORMANCE           |   |      |           |      |       |
| Harmonic Distortion (HD2/HD3)          | When used differentially, $f_C = 100 \text{ kHz}$ , $V_{OUT} = 1 \text{ V p-p}$ |      | -117/-116 |      | dBc   |
|  | When used differentially, $f_C = 1$ MHz, $V_{OUT} = 1$ V p-p                    |      | -80/-85   |      | dBc   |
|  | When P1 is used, $f_c = 100 \text{ kHz}$ , $V_{OUT} = 500 \text{ mV p-p}$       |      | -108/-115 |      | dBc   |
|  | When P1 is used, $f_C = 1$ MHz, $V_{OUT} = 500$ mV p-p                          |      | -80/-83   |      | dBc   |
|  | When M1 is used, $f_C = 100 \text{ kHz}$ , $V_{OUT} = 500 \text{ mV p-p}$       |      | -103/-107 |      | dBc   |
|  | When M1 is used, $f_C = 1$ MHz, $V_{OUT} = 500$ mV p-p                          |      | -75/-78   |      | dBc   |
| Referred to Input (RTI) Voltage Noise  | For P1, f = 10 Hz   |      | 60        |      | nV/√⊦ |
| , , ,                                  | For P1, f = 100 kHz   |      | 5.2       |      | nV/√⊦ |
| Referred to Output (RTO) Voltage Noise | For P1 and M1, f = 10 Hz, measured at VOUT2                                     |      | 140       |      | nV/√⊦ |
| , , ,                                  | For P1 and M1, f = 100 kHz, measured at VOUT2                                   |      | 18        |      | nV/√H |
| Input Current Noise                    | f = 100 kHz, referred to P1   |      | 1.1       |      | pA/√⊦ |
| DC PERFORMANCE                         |   |      |           |      |       |
| Output Offset Voltage                  | Differential  |      | 0.15      | 0.75 | mV    |
| Input Offset Voltage Drift             | Differential  |      | 0.6       | 16   | μV/°C |
| Output Offset Voltage                  | Single-ended, P1 only   |      | 60        | 275  | μV    |
|  | Single-ended, M1 only   |      | 70        | 250  | μV    |
| Input Offset Voltage Drift             | Single-ended, P1 only   |      | 0.1       | 5.9  | μV/°C |
|  | Single-ended, M1 only   |      | 0.3       | 4.5  | μV/°C |
| Input Bias Current                     | P1 only at VIN1 pin   |      | 60        | 230  | nA    |
| <b>,</b>                               | P1 only at RF1 pin  |      | 60        | 350  | nA    |
|  | M1 only at REF pin  |      | 60        | 200  | nA    |
| Input Offset Current                   | P1 only   |      | 60        | 270  | nA    |
| Open-Loop Gain                         | P1 only, V <sub>OUT</sub> = 1.5 V to 3.5 V                                      | 94   | 100       | _, • | dB    |
| Gain                                   | M1 only   | 1.99 | 1.9995    | 2.01 | V/V   |
| Gain Error                             | ,   | -0.5 |           | +0.5 | %     |
| Gain Error Drift                       |   |      | 0.6       | 3.4  | ppm/° |

| Parameter                             | Test Conditions/Comments <sup>1</sup>                                    | Min          | Тур            | Max | Unit   |
|---------------------------------------|--|--------------|----------------|-----|--------|
| INPUT CHARACTERISTICS                 |  |              |                |     |        |
| Input Resistance                      | VIN1 and REF   |              | 200            |     | ΜΩ     |
| Input Capacitance                     | VIN1 and REF   |              | 1.4            |     | pF     |
| Input Common-Mode Voltage Range       |  |              | 0 to 3.9       |     | V      |
| Common-Mode Rejection Ratio           | For P1, $V_{CM} = \pm 0.5 \text{ V}$                                     | 84           | 94             |     | dB     |
| OUTPUT CHARACTERISTICS                |  |              |                |     |        |
| Output Voltage Swing                  | $R_L = no load$ , single-ended   | 0.15 to 4.85 | 0.125 to 4.875 |     | V      |
|                                       | $R_L = 500 \Omega$ , single-ended  | 0.28 to 4.72 | 0.24 to 4.76   |     | V      |
| Output Common-Mode Voltage Range      |  |              | 0 to 3.9       |     | V      |
| Linear Output Current                 | For P1or M1, $V_{OUT} = 1 \text{ V p-p}$ , 60 dB SFDR                    |              | 4              |     | mA rms |
|                                       | Differential output, V <sub>OUT</sub> = 1 V p-p, 60 dB SFDR              |              | 10             |     | mA rms |
| Short-Circuit Current                 | For P1 or M1, sinking/sourcing   |              | 41/63          |     | mA     |
| Capacitive Load Drive                 | When used differentially at each VOUTx, 30% overshoot, Vout = 100 mV p-p |              | 33             |     | pF     |
|                                       | When P1/M1 is used, 30% overshoot, $V_{OUT} = 50$ mV p-p                 |              | 47             |     | pF     |
| POWER SUPPLY                          |  |              |                |     |        |
| Operating Range                       |  | 3.3          |                | 12  | V      |
| Positive Power Supply Rejection Ratio | For P1   | 86           | 104            |     | dB     |
|                                       | For M1   | 80           | 94             |     | dB     |
| Negative Power Supply Rejection Ratio | For P1   | 80           | 92             |     | dB     |
|                                       | For M1   | 76           | 88             |     | dB     |

 $<sup>^{\</sup>rm 1}\,{\rm P1}$  and M1 within this table refer to the amplifiers shown in Figure 1.

#### **TIMING SPECIFICATIONS**

All input signals are specified with  $t_R = t_F = 2$  ns (10% to 90% of DVDD) and timed from a voltage threshold level of  $V_{TH} = 1.3$  V at DVDD = 3.3 V or  $V_{TH} = 1.7$  V at DVDD = 5 V. Guaranteed by characterization; not production tested. See Figure 2, Figure 3, and Figure 4.

Table 9.

|                              |  | DVDD = 3.3 V |     | DVDD = 5 V |     |      |
|------------------------------|--|--------------|-----|------------|-----|------|
| Parameter                    | Description <sup>1</sup>   | Min          | Max | Min        | Max | Unit |
| t <sub>1</sub>               | SCLK period.   | 20           |     | 20         |     | ns   |
| $t_2$                        | SCLK positive pulse width.   | 10           |     | 10         |     | ns   |
| t <sub>3</sub>               | SCLK negative pulse width.   | 10           |     | 10         |     | ns   |
| t <sub>4</sub>               | CS setup time. The time required to begin sampling data after CS goes low.   | 1            |     | 1          |     | ns   |
| <b>t</b> <sub>5</sub>        | $\overline{CS}$ hold time. The amount of time required for $\overline{CS}$ to be held low after the last data  | 7            |     | 5          |     | ns   |
|                              | bit is sampled before bringing $\overline{CS}$ high. Data is latched on the $\overline{CS}$ rising edge. If $\overline{LATCH}$ is held low, data is also applied on the $\overline{CS}$ rising edge. |              |     |            |     |      |
| t <sub>6</sub>               | CS positive pulse width. The amount of time required between consecutive words.  | 2            |     | 1          |     | ns   |
| t <sub>7</sub>               | Data setup time. The amount of time the data bit (SDI) must be set before sampling on the falling edge of SCLK.  | 1            |     | 1          |     | ns   |
| t <sub>8</sub>               | Data hold time. The amount of time SDI must be held after the falling edge of SCLK for valid data to be sampled.   | 2            |     | 2          |     | ns   |
| t <sub>9</sub>               | Data latched to the internal switches updated. The amount of time it takes from the latched data being applied until the internal switches are updated.  |              | 145 |            | 140 | ns   |
|                              | LATCH disabled referenced from the rising edge of CS.  |              |     |            |     |      |
|                              | LATCH enabled referenced from the falling edge of LATCH.   |              |     |            |     |      |
| t <sub>10</sub>              | LATCH negative pulse width.  | 3            |     | 3          |     | ns   |
| t <sub>11</sub> <sup>2</sup> | SCLK rising edge to SDO valid. The amount of time between the SCLK rising edge and the valid SDO transitions ( $CL_{SDO}^3 = 20 \text{ pF}$ ).   |              | 15  |            | 10  | ns   |
| t <sub>12</sub>              | CS rising edge to the SCLK falling edge. The amount of time required to prevent a 25 <sup>th</sup> SCLK edge from being recognized (only 24 bits allowed for valid word).                            | 1            |     | 1          |     | ns   |

<sup>&</sup>lt;sup>1</sup> When referring to a single function of a multifunction pin, only the portion of the pin name that is relevant to the specification is listed. For full pin names of multifunction pins, refer to the Pin Configuration and Function Descriptions section.

#### **Timing Diagrams for Serial Mode**

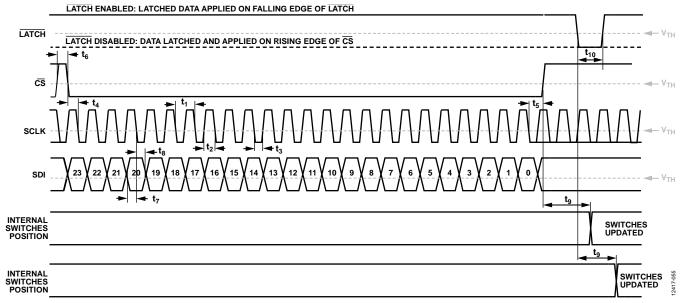


Figure 2. Write Operation

<sup>&</sup>lt;sup>2</sup> This is while in daisy-chain mode and in readback mode.

<sup>&</sup>lt;sup>3</sup> CL<sub>SDO</sub> is the capacitive load on the SDO output.

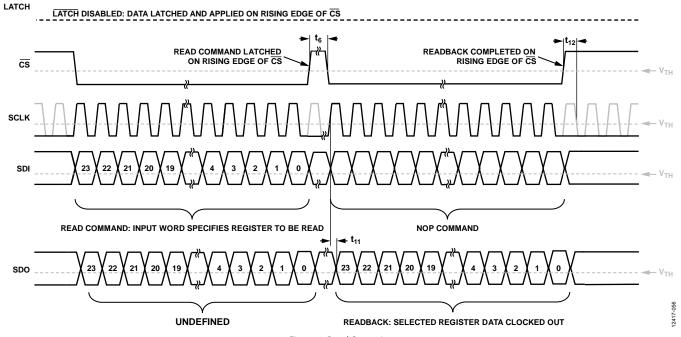


Figure 3. Read Operation

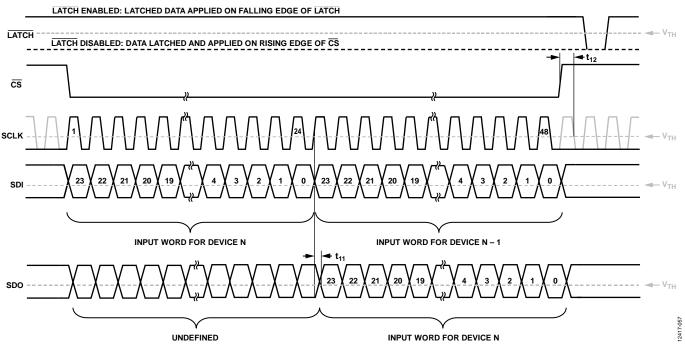


Figure 4. Daisy-Chain Timing Diagram

#### ABSOLUTE MAXIMUM RATINGS

Table 10.

| Parameter                                      | Rating            |
|--|-------------------|
| Supply Voltage                                 | 14 V              |
| Power Dissipation                              | See Figure 5      |
| Common-Mode Input Voltage                      | $\pm Vs \pm 0.3V$ |
| Differential Input Voltage                     | ±0.7 V            |
| Input Current (IN-N, IN-P, VIN1, RF1, and REF) | 20 mA             |
| Storage Temperature Range                      | −65°C to +125°C   |
| Operating Temperature Range                    | −40°C to +85°C    |
| Lead Temperature (Soldering, 10 sec)           | 300°C             |
| Junction Temperature                           | 150°C             |

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

#### THERMAL RESISTANCE

 $\theta_{JA}$  is specified for the worst-case conditions, that is,  $\theta_{JA}$  is specified for a device soldered in a circuit board for surface-mount packages. Table 11 lists the  $\theta_{JA}$  for the ADA4350.

**Table 11. Thermal Resistance** 

| Package Type  | θ <sub>JA</sub> | Unit |
|---------------|-----------------|------|
| 28-Lead TSSOP | 72.4            | °C/W |

#### **MAXIMUM POWER DISSIPATION**

The maximum safe power dissipation for the ADA4350 is limited by the associated rise in junction temperature (T<sub>1</sub>) on the die. At approximately 150°C, which is the glass transition temperature, the properties of the plastic change. Even temporarily exceeding this temperature limit may change the stresses that the package exerts on the die, permanently shifting the parametric performance of the ADA4350. Exceeding a junction temperature of 175°C for an extended period can result in changes in silicon devices, potentially causing degradation or loss of functionality.

The power dissipated in the package ( $P_D$ ) is the sum of the quiescent power dissipation and the power dissipated in the die due to the ADA4350 output load drive.

The quiescent power dissipation is the voltage between the supply pins  $(\pm V_s)$  multiplied by the quiescent current (I<sub>s</sub>).

 $P_D = Quiescent Power + (Total Drive Power - Load Power)$ 

$$P_D = \left(\pm V_S \times I_S\right) + \left(\frac{\pm V_S}{2} \times \frac{V_{OUT}}{R_L}\right) - \frac{{V_{OUT}}^2}{R_L}$$

Consider rms output voltages. If  $R_L$  is referenced to  $-V_S$ , as in single-supply operation, the total drive power is  $+V_S \times I_{OUT}$ . If the rms signal levels are indeterminate, consider the worst case, when  $V_{OUT} = +V_S/4$  for  $R_L$  to midsupply for dual supplies and  $V_{OUT} = +V_S/2$  for single supply.

$$P_D = \left(+V_S \times I_S\right) + \frac{\left(V_{OUT}\right)^2}{R_L}$$

Airflow increases heat dissipation, effectively reducing  $\theta_{JA}$ . In addition, more metal directly in contact with the package leads and exposed pad from metal traces, through holes, ground, and power planes reduces  $\theta_{JA}$ .

Figure 5 shows the maximum safe power dissipation in the package vs. the ambient temperature on a JEDEC standard 4-layer board.  $\theta_{JA}$  values are approximations.

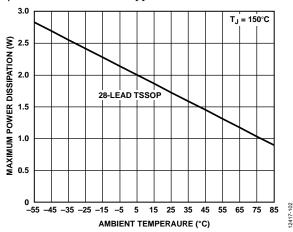


Figure 5. Maximum Power Dissipation vs. Ambient Temperature for a 4-Layer Board

#### **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

### PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

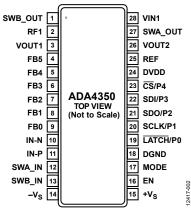


Figure 6. Pin Configuration

**Table 12. Pin Function Descriptions** 

| Pin No. | Mnemonic        | Description  |
|---------|-----------------|--|
| 1       | SWB_OUT         | Switch Group B (S3 to S5 and S9 to S11) Output.  |
| 2       | RF1             | Feedback Resistor for Output Differential Amplifier.                                   |
| 3       | VOUT1           | Differential Amplifier Output 1.   |
| 4       | FB5             | Feedback Pin 5 for FET Input Amplifier.  |
| 5       | FB4             | Feedback Pin 4 for FET Input Amplifier.  |
| 6       | FB3             | Feedback Pin 3 for FET Input Amplifier.  |
| 7       | FB2             | Feedback Pin 2 for FET Input Amplifier.  |
| 8       | FB1             | Feedback Pin 1 for FET Input Amplifier.  |
| 9       | FB0             | Feedback Pin 0 for FET Input Amplifier.  |
| 10      | IN-N            | FET Input Amplifier Inverting Input.   |
| 11      | IN-P            | FET Input Amplifier Noninverting Input.  |
| 12      | SWA_IN          | Switch Group A (S0 to S2 and S6 to S8) Input.  |
| 13      | SWB_IN          | Switch Group B (S3 to S5 and S9 to S11) Input.   |
| 14      | -V <sub>S</sub> | Analog Negative Supply.  |
| 15      | +V <sub>S</sub> | Analog Positive Supply.  |
| 16      | EN              | Enable Pin.  |
| 17      | MODE            | Mode Pin. Use this pin to switch between the SPI interface and the parallel interface. |
| 18      | DGND            | Digital Ground.  |
| 19      | LATCH/P0        | Latch Bit in the Serial Mode (LATCH). Parallel Data Bit 0 in parallel mode (P0).       |
| 20      | SCLK/P1         | Digital Clock in Serial Mode (SCLK). Parallel Data Bit 1 in parallel mode (P1).        |
| 21      | SDO/P2          | Serial Data Out in Serial Mode (SDO). Parallel Data Bit 2 in parallel mode (P2).       |
| 22      | SDI/P3          | Serial Data In in Serial Mode (SDI). Parallel Data Bit 3 in parallel mode (P3).        |
| 23      | CS/P4           | Select Bit in Serial Mode (CS). Parallel Data Bit 4 in parallel mode (P4).             |
| 24      | DVDD            | Digital Positive Supply.   |
| 25      | REF             | Reference for the ADC Driver at M1.  |
| 26      | VOUT2           | Differential Amplifier Output 2.   |
| 27      | SWA_OUT         | Switch Group A (S0 to S2 and S6 to S8) Output.   |
| 28      | VIN1            | Differential Amplifier Noninverting Input.   |

#### TYPICAL PERFORMANCE CHARACTERISITICS

#### **FULL SYSTEM**

These plots are for the full system, which includes the FET input amplifier, the switching network, and the ADC driver. Unless otherwise stated,  $R_L = 1 \text{ k}\Omega$  differential. For  $Vs = \pm 5 \text{ V}$ , DVDD = +5 V, and for  $Vs = \pm 5 \text{ V}$  (or  $\pm 2.5 \text{ V}$ ), DVDD = +3.3 V.

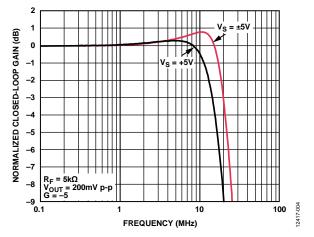


Figure 7. Small Signal Frequency Response for Various Supplies, See Test Circuit in Figure 50

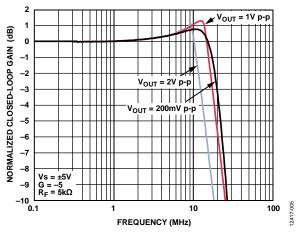


Figure 8. Frequency Response for Various Voltage Outputs, See Test Circuit in Figure 50

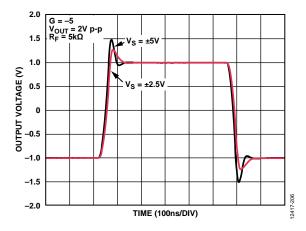


Figure 9. Large Signal Step Response, G = -5 for Various Supplies

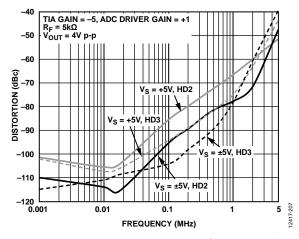


Figure 10. Harmonic Distortion vs. Frequency for Various Supplies, See Test Circuit in Figure 49

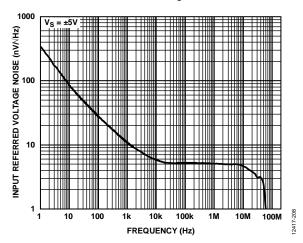


Figure 11. Input Referred Voltage Noise vs. Frequency

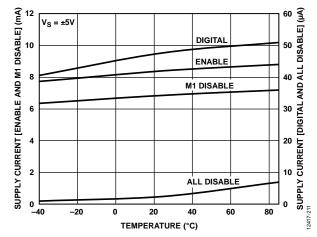


Figure 12. Supply Current vs. Temperature at Different Modes

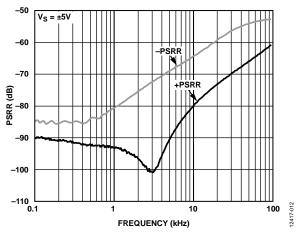


Figure 13. PSRR vs. Frequency

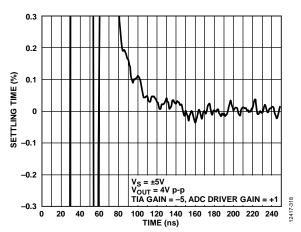


Figure 14. 0.1% Settling Time, See Test Circuit in Figure 50

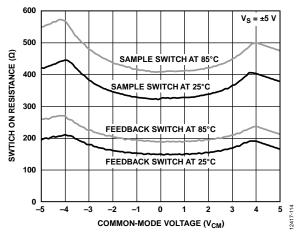


Figure 15. Switch On-Resistance vs. Common-Mode Voltage at Switches for Various Temperature

#### **FET INPUT AMPLIFIER**

Unless otherwise stated,  $R_L = 1 \text{ k}\Omega$ . For  $Vs = \pm 5 \text{ V}$ , DVDD = +5 V, and for  $Vs = \pm 2.5 \text{ V}$ , DVDD = +3.3 V.

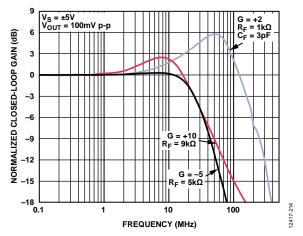


Figure 16. Small Signal Frequency Response for Various Gains,  $V_5 = \pm 5 V$ , See Test Circuit Diagrams in Figure 51 and Figure 52

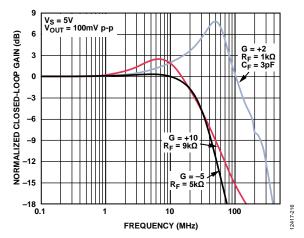


Figure 17. Small Signal Frequency Response for Various Gains,  $V_5 = 5 V$ , See Test Circuit Diagrams in Figure 51 and Figure 52

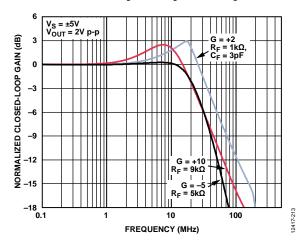


Figure 18. Large Signal Frequency Response for Various Gains,  $V_s = \pm 5 V$ , See Test Circuit Diagrams in Figure 51 and Figure 52

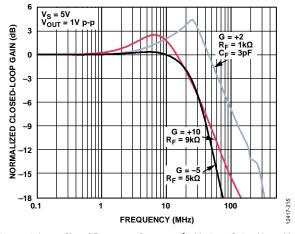


Figure 19. Large Signal Frequency Response for Various Gains,  $V_S = 5$  V, See Test Circuit Diagrams in Figure 51 and Figure 52

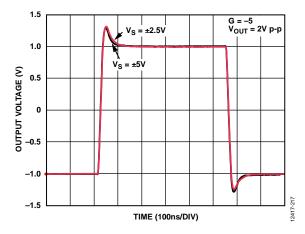


Figure 20. Large Signal Step Response for Various Supplies, G = -5

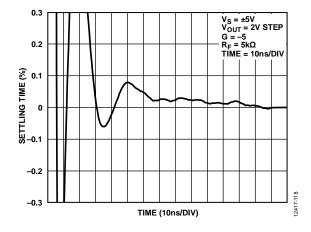


Figure 21. 0.1% Settling Time

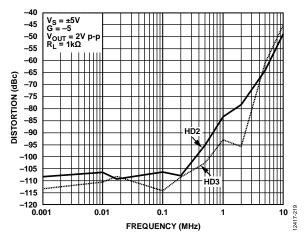


Figure 22. Distortion (HD2/HD3) vs. Frequency, G = -5

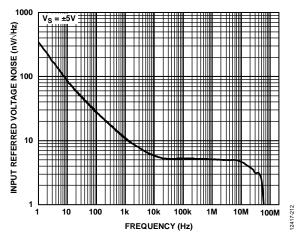


Figure 23. Input Voltage Noise

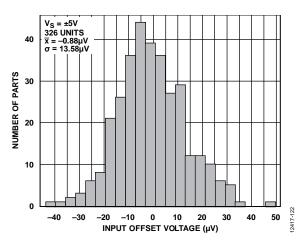


Figure 24. Input Offset Voltage

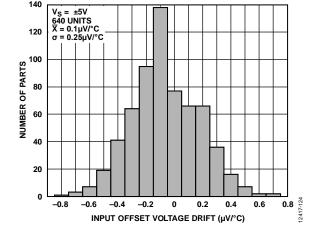


Figure 25. Input Offset Voltage Drift

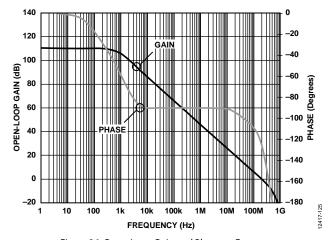


Figure 26. Open-Loop Gain and Phase vs. Frequency

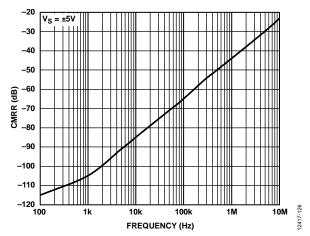


Figure 27. CMRR vs Frequency

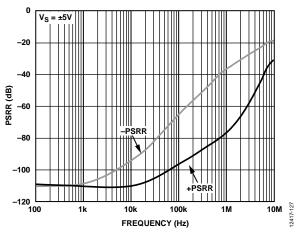


Figure 28. PSRR vs Frequency

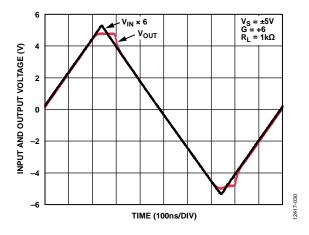


Figure 29. Output Overdrive Recovery When Used as an Amplifier

#### **ADC DRIVER**

Unless stated otherwise,  $R_L = 1 \text{ k}\Omega$  differential, and  $R_L = 500 \Omega$  when single-ended. For  $V_S = \pm 5 \text{ V}$ , DVDD = +5 V, and for  $V_S = +5 \text{ V}$  (or  $\pm 2.5 \text{ V}$ ), DVDD = +3.3 V.

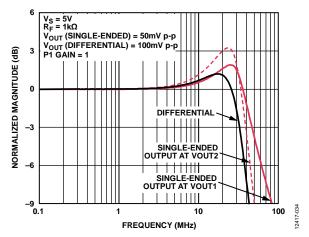


Figure 30. Small Signal Frequency Response,  $V_S = 5 V$ 

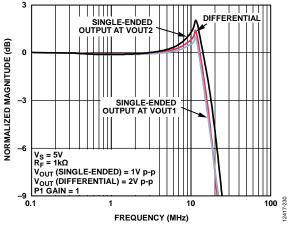


Figure 31. Large Signal Frequency Response,  $V_S = 5 V$ 

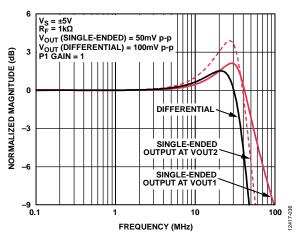


Figure 32. Small Signal Frequency Response,  $V_S = \pm 5 V$ 

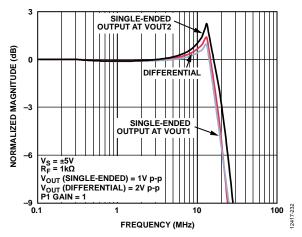


Figure 33. Large Signal Frequency Response,  $V_S = \pm 5 V$ 

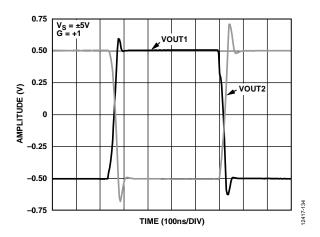


Figure 34. Large Signal Step Response (Single-Ended Output),  $V_S = \pm 5 V$ 

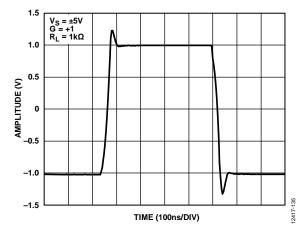


Figure 35. Large Signal Step Response (Differential Output),  $V_S = \pm 5 V$ 

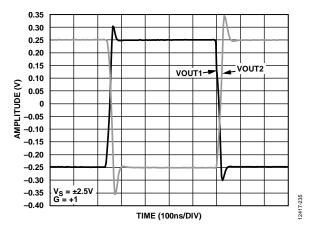


Figure 36. Large Signal Step Response (Single-Ended Output),  $V_S = \pm 2.5 \text{ V}$ 

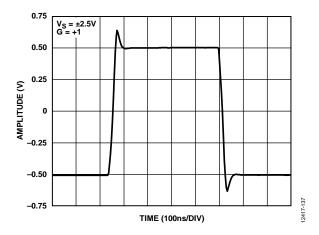


Figure 37. Large Signal Step Response (Differential Output),  $V_S = \pm 2.5 \text{ V}$ 

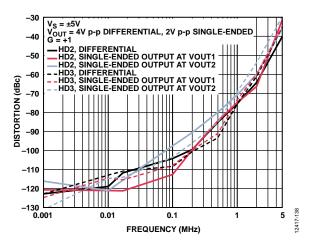


Figure 38. Harmonic Distortion vs. Frequency

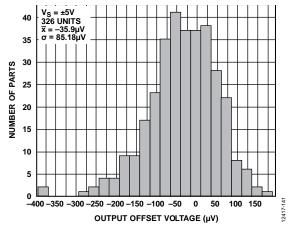


Figure 39. Differential Output Offset Voltage

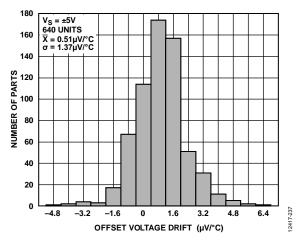


Figure 40. Differential Output Offset Voltage Drift

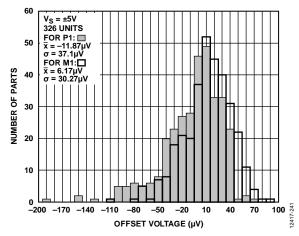


Figure 41. Single-Ended Output Offset Voltage

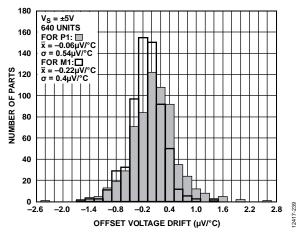


Figure 42. Single-Ended Offset Voltage Drift

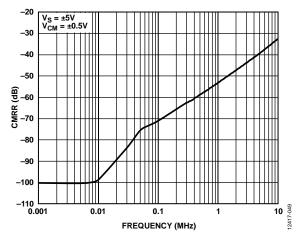


Figure 43. CMRR vs. Frequency

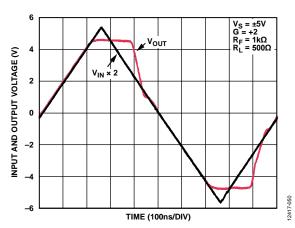


Figure 44. Output Overdrive Recovery (P1 Only)

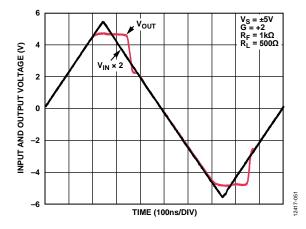


Figure 45. Output Overdrive Recovery (M1 Only)

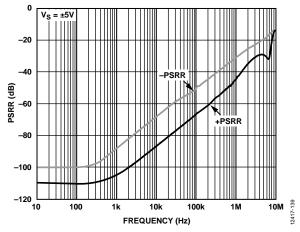


Figure 46. PSRR vs. Frequency (P1 Only)

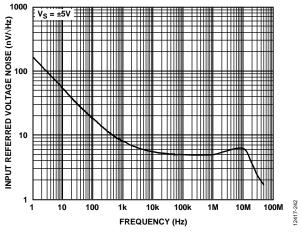


Figure 47. Input Referred Voltage Noise vs. Frequency, P1 Only, See Test Circuit Diagram in Figure 53

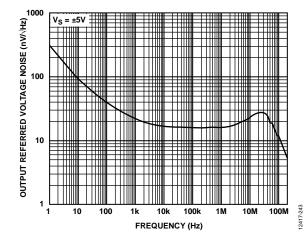


Figure 48. Output Referred Voltage Noise vs. Frequency, P1 and M1, See Test Circuit Diagram in Figure 54

#### **TEST CIRCUITS**

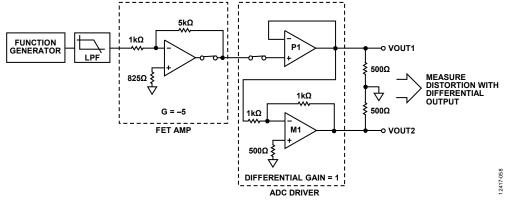


Figure 49. Harmonic Distortion for Full System

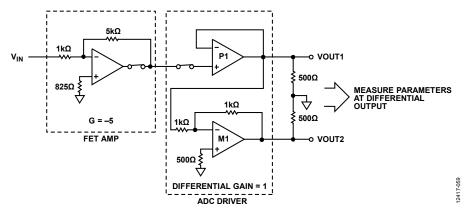


Figure 50. Full System Measurement for Other Parameters

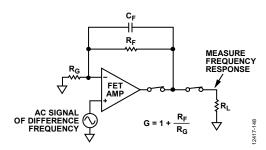


Figure 51. Frequency Response for FET Input Amplifier, Noninverting Gain Configuration

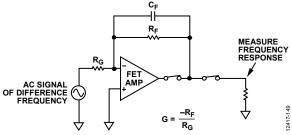


Figure 52. Frequency Response for FET Input Amplifier, Inverting Gain Configuration

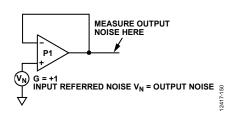


Figure 53. Input Referred Voltage Noise for P1

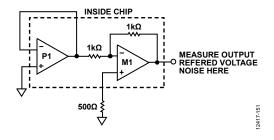
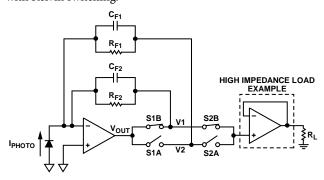


Figure 54. Output Referred Voltage Noise for P1 and M1

## THEORY OF OPERATION KELVIN SWITCHING TECHNIQUES

Traditional gain selectable amplifiers use analog switches in a feedback loop to connect discrete external resistors and capacitors to the inverting input by selecting the appropriate feedback path. This approach introduces several errors due to the nonideal nature of the analog switches in the loop. For example, the on-resistance of the analog switch causes voltage and temperature dependent gain errors, while the leakage current causes offset errors, especially at high temperature. The Kelvin switching technique solves this problem by introducing two switches in each gain selection loop, one to connect the transimpedance/ op amp output to the feedback network, and the other to connect the feedback network output to the downstream components. Figure 55 shows a programmable gain transimpedance amplifier with Kelvin switching.



NOTES

1. S1A, S1B, S2A, AND S2B ARE THE ANALOG SWITCHES.

R<sub>FX</sub> ARE THE FEEDBACK RESISTORS SPECIFIC TO EACH

TRANSIMPEDANCE PATH. C<sub>FX</sub> ARE THE FEEDBACK CAPACITORS

SPECIFIC TO EACH TRANSIMPEDANCE PATH.

Figure 55. Programmable Gain Transimpedance Amplifier with Kelvin Switching

Although this technique requires using twice as many switches, the voltage (Vx) in the center node is no longer switch dependent; it is only dependent on the current across the selected resistor (see Equation 1 through Equation 3).

$$V_{OUT} = -I_{PHOTO} \times (R_{F2} + R_{S1B}) \tag{1}$$

$$V1 = V_{OUT} \times (R_{F2}/(R_{F2} + R_{S1B})) \tag{2}$$

Substituting Equation 1 into Equation 2,

$$V1 = -I_{PHOTO} \times R_{F2} \tag{3}$$

where:

 $V_{OUT}$  is the output of the first amplifier.  $I_{PHOTO}$  is the current from the photodiode.  $R_{F2}$  is the feedback resistor of Transimpedance Path 2.  $R_{S1B}$  is the switch resistance of the S1B switch.

The switches shown on the right (S2A and S2B) in Figure 55 only have a small output impedance and contribute negligible error if the amplifier drives a high impedance load. In the case of the ADA4350, the high impedance load is the integrated ADC driver.

#### APPLICATIONS INFORMATION

#### **CONFIGURING THE ADA4350**

Refer to the UG-655 User Guide for details on the basic configuration of the ADA4350, and how to use the evaluation board. For more details on configuring the ADC driver in a different gain setting, refer to the ADA4941-1 data sheet.

The gain settings of the ADA4350 can be chosen via the SPI interface or manually through a 5-lead DIP switch.

## SELECTING THE TRANSIMPEDANCE GAIN PATHS MANUALLY OR THROUGH THE PARALLEL INTERFACE

In the manual mode (or parallel mode), only five out of the six transimpedance paths can be accessed (FB0 to FB4). Figure 56 shows the simplified schematics of the ADA4350 and the positions of FB0 to FB4. In this example, the first two feedback paths (FB0 and FB1) are configured as two different transimpedance gain paths.

To operate in manual mode or in parallel mode, set the EN pin (Pin 16) and the MODE pin (Pin 17) to Logic 1. In this mode, Pin 19 to Pin 23 represent P0 through P4, respectively. To select one gain, set the corresponding Px pin to Logic 1, and set all other Px pins to Logic 0. Table 13 shows the relationship between the gain select switches (P0 through P4) and the gain path selected.

Setting more than one Px pin to Logic 1 results in connecting the selected gain paths in parallel.

Table 13. Manual Mode or Parallel Mode Operation

| Bit On | Switch Closed | Gain Path Selected |
|--------|---------------|--------------------|
| P0     | S0 and S6     | FB0                |
| P1     | S1 and S7     | FB1                |
| P2     | S2 and S8     | FB2                |
| P3     | S3 and S9     | FB3                |
| P4     | S4 and S10    | FB4                |

## SELECTING THE TRANSIMPEDANCE GAIN PATHS THROUGH THE SPI INTERFACE (SERIAL MODE)

For serial mode operation, set the EN pin (Pin 16) to Logic 1 and the MODE pin (Pin 17) to Logic 0. In serial mode, Pin 19 is LATCH, Pin 20 is SCLK, Pin 21 is SDO, Pin 22 is SDI, and Pin 23 is CS. Serial mode operation uses a 24-bit command to configure each individual switch, S0 through S11, as well as additional options. Table 14 shows the 24-bit map used in serial mode operation. Table 15 shows the example codes used to select the various transimpedance gain paths.

Multifunction pin names may be referenced by their relevant function only.

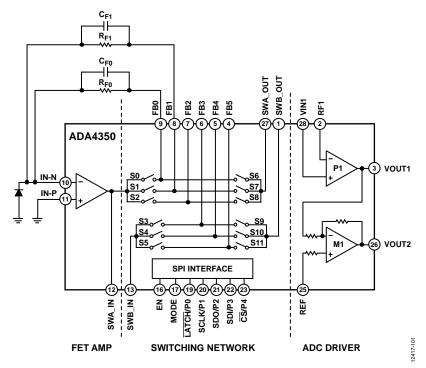


Figure 56. Simplified Schematic

Table 14. 24-Bit Map Used in Serial Mode Operation

| Bit No. | Function   | Default Setting |
|---------|--|-----------------|
| 1       | S0 on/off control. Write 1 to this bit to close Switch S0.   | 0               |
| 2       | S1 on/off control. Write 1 to this bit to close Switch S1.   | 0               |
| 3       | S2 on/off control. Write 1 to this bit to close Switch S2.   | 0               |
| 4       | S3 on/off control. Write 1 to this bit to close Switch S3.   | 0               |
| 5       | S4 on/off control. Write 1 to this bit to close Switch S4.   | 0               |
| 6       | S5 on/off control. Write 1 to this bit to close Switch S5.   | 0               |
| 7       | S6 on/off control. Write 1 to this bit to close Switch S6.   | 0               |
| 8       | S7 on/off control. Write 1 to this bit to close Switch S7.   | 0               |
| 9       | S8 on/off control. Write 1 to this bit to close Switch S8.   | 0               |
| 10      | S9 on/off control. Write 1 to this bit to close Switch S9.   | 0               |
| 11      | S10 on/off control. Write 1 to this bit to close Switch S10.   | 0               |
| 12      | S11 on/off control. Write 1 to this bit to close Switch S11.   | 0               |
| 13      | Reserved. Set to logic low.  | 0               |
| 14      | Optional internal 1 pF feedback capacitor between the inverting input and the output of the amplifier. Write 1 to this bit to turn the capacitor on. | 0               |
| 15      | Disable the SDO pin. Write 1 to this bit to disable the SDO pin.   | 0               |
| 16      | Disable the M1 amplifier. Write 1 to this bit to disable the M1 amplifier.   | 0               |
| 17      | Reserved. Set to logic low.  | 0               |
| 18      | Reserved. Set to logic low.  | 0               |
| 19      | Reserved. Set to logic low.  | 0               |
| 20      | Reserved. Set to logic low.  | 0               |
| 21      | Reserved. Set to logic low.  | 0               |
| 22      | Reserved. Set to logic low.  | 0               |
| 23      | Reserved. Set to logic low.  | 0               |
| 24      | Read/write bit. Set to 1 to read and set to 0 to write.  | 0               |

**Table 15. Serial Mode Operation** 

| Command (Hex Code Format, B23B0) | Switch Closed | Gain Path Selected                           |
|----------------------------------|---------------|--|
| 00 00 41(MSB Side)               | S0 and S6     | FB0  |
| 00 20 41                         | S0 and S6     | FB0, optional internal feedback capacitor on |
| 00 00 82                         | S1 and S7     | FB1  |
| 00 01 04                         | S2 and S8     | FB2  |
| 00 02 08                         | S3 and S9     | FB3  |
| 00 04 10                         | S4 and S10    | FB4  |
| 00 08 40                         | S5 and S11    | FB5  |

#### **SPICE MODEL**

The SPICE model only supports parallel mode operation. Pin P5 enables parallel mode and allows full switching network functionality. The EN and MODE inputs are internally set to high and low, respectively, and are not accessible in this model.

Figure 57 shows the recommended symbol pins when creating the ADA4350 symbol in the SPICE simulator.

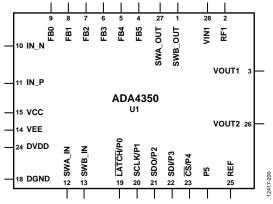


Figure 57. Recommended Symbol Layout

**Table 16. Model Pin Descriptions** 

| Symbol Pin | Model Node | Pin No.        | Mnemonic |
|------------|------------|----------------|----------|
| 1          | N10        | 10             | IN_N     |
| 2          | N11        | 11             | IN_P     |
| 3          | VCC        | 15             | VCC      |
| 4          | VEE        | 14             | VEE      |
| 5          | VDD        | 24             | DVDD     |
| 6          | DGND       | 18             | DGND     |
| 7          | N12        | 12             | SWA_IN   |
| 8          | N13        | 13             | SWB_IN   |
| 9          | PO         | 19             | LATCH/P0 |
| 10         | P1         | 20             | SCLK/P1  |
| 11         | P2         | 21             | SDO/P2   |
| 12         | Р3         | 22             | SDI/P3   |
| 13         | P4         | 23             | CS/P4    |
| 14         | P5         | Not applicable | P5       |
| 15         | N25        | 25             | REF      |
| 16         | N26        | 26             | VOUT2    |
| 17         | N3         | 3              | VOUT1    |
| 18         | N2         | 2              | RF1      |
| 19         | N28        | 28             | VIN1     |
| 20         | 27         | 27             | SWA_OUT  |
| 21         | 1          | 1              | SWB_OUT  |
| 22         | 4          | 4              | FB5      |
| 23         | 5          | 5              | FB4      |
| 24         | 6          | 6              | FB3      |
| 25         | 7          | 7              | FB2      |
| 26         | 8          | 8              | FB1      |
| 27         | 9          | 9              | FB0      |

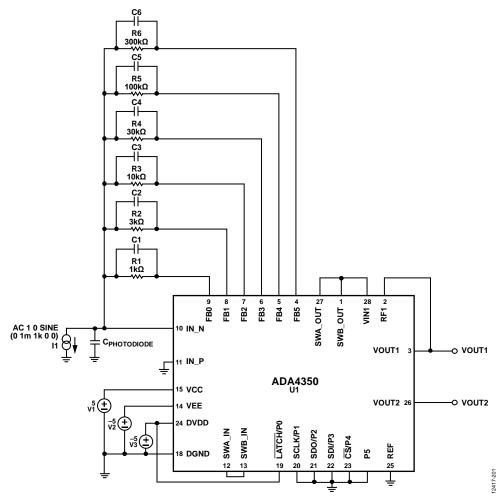


Figure 58. SPICE Schematic Example to Test Basic Functionality

#### TRANSIMPEDANCE AMPLIFIER DESIGN THEORY

Because its low input bias current minimizes the dc error at the preamp output, the ADA4350 works well in photodiode preamp applications. In addition, its high gain bandwidth product and low input capacitance maximizes the signal bandwidth of the photodiode preamp. Figure 59 shows the transimpedance amplifier model of the ADA4350.

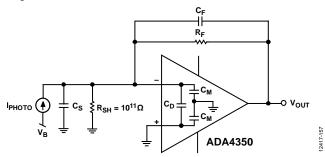


Figure 59. Transimpedance Amplifier Model of the ADA4350

The basic transfer function in Equation 4 describes the transimpedance gain of the photodiode preamp.

$$V_{OUT} = \frac{I_{PHOTO} \times R_F}{1 + sC_E R_E} \tag{4}$$

where:

 $I_{PHOTO}$  is the output current of the photodiode.

 $R_F$  is the feedback resistor.

 $C_F$  is the feedback capacitance.

The signal bandwidth is  $1/(R_F \times C_F)$ , as determined by Equation 4. In general, set  $R_F$  such that the maximum attainable output voltage corresponds to the maximum diode current,  $I_{PHOTO}$ , allowing the use of the full output swing.

The signal bandwidth attainable with this preamp is a function of  $R_F$ , the gain bandwidth product ( $f_{GBW}$ ) of the amplifier, and the total capacitance at the amplifier summing junction, including  $C_S$  and the amplifier input capacitance of  $C_D$  and  $C_M$ .  $R_F$  and the total capacitance produce a pole with the loop frequency ( $f_P$ ).

$$f_P = 1/2\pi R_F C_S \tag{5}$$

With the additional pole from the open-loop response of the amplifier, the two-pole system results in peaking and instability due to an insufficient phase margin (see gray lines for the noise gain and phase in Figure 60).

Adding  $C_F$  to the feedback loop creates a zero in the loop transmission that compensates for the effect of the input pole, which stabilizes the photodiode preamp design because of the increased phase margin (see the gray lines for the noise gain and phase in Figure 61). It also sets the signal bandwidth,  $f_Z$  (see the I to V gain line for the signal gain in Figure 61). The signal bandwidth and the zero frequency,  $f_Z$ , are determined by

$$f_z = \frac{1}{2\pi R_F C_F} \tag{6}$$

Equating the zero frequency,  $f_Z$ , with the  $f_X$  frequency maximizes the signal bandwidth with a 45° phase margin. Calculate  $f_X$  as follows because  $f_X$  is the geometric mean of  $f_P$  and  $f_{GBW}$ :

$$f_x = \sqrt{f_P \times f_{GRW}} \tag{7}$$

By combining Equation 5, Equation 6, and Equation 7, the  $C_F$  value that produces  $f_X$  is defined by

$$C_F = \sqrt{\frac{C_S}{2\pi \times R_F \times f_{GBW}}} \tag{8}$$

The frequency response in this case shows approximately 2 dB peaking and 15% overshoot. Doubling C<sub>F</sub> and cutting the bandwidth in half results in a flat frequency response with approximately 5% transient overshoot.

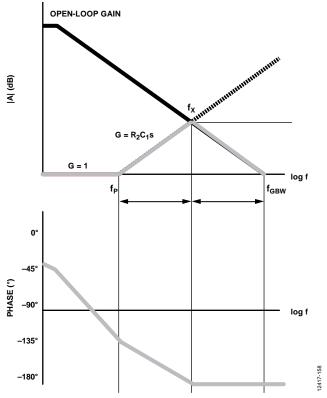


Figure 60. Noise Gain and Phase Bode Plot of the Transimpedance Amplifier Design Without Compensation

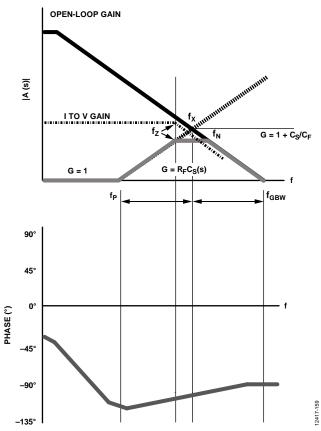


Figure 61. Signal and Noise Gain and Phase of the Transimpedance Amplifier Design with Compensation

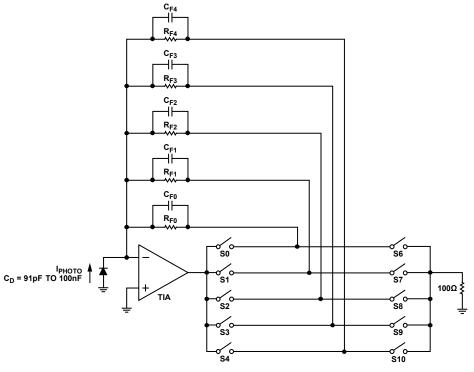
The dominant output noise sources in the transimpedance amplifier design are the input voltage noise of the amplifier,  $V_{\text{NOISE}},$  and the resistor noise due to  $R_{\text{F}}.$  The effect due to the current noise is negligible in comparison. The gray line in Figure 61 shows the noise gain and phase over frequencies for the transimpedance amplifier. The noise bandwidth is at the  $f_{\rm N}$  frequency, and is calculated by

$$f_N = \frac{f_{GBW}}{\left(C_S + C_F\right)/C_F} \tag{9}$$

Table 17 shows the dominant noise sources ( $R_F$  and  $V_{NOISE}$ ) for the transimpedance amplifier when it has a 45° phase margin for the maximum bandwidth, and in this case,  $f_Z = f_X = f_N$ .

Table 17. RMS Noise Contributions of Transimpedance Amplifier

| Contributor        | Expression  |
|--------------------|---|
| R <sub>F</sub>     | $\sqrt{4kT \times R_F \times f_N \times \frac{\pi}{2}}$   |
| V <sub>NOISE</sub> | $V_{NOISE} \times \frac{\left(C_S + C_M + C_F + 2C_D\right)}{C_F} \times \sqrt{\frac{\pi}{2} \times f_N}$ |



NOTES 1.  $R_{\rm Fx}$  are the feedback resistors specific to each transimpedance path.  $C_{\rm Fx}$  are the feedback capacitors specific to each transimpedance path.

Figure 62. ADA4350 Configured as a Transimpedance Amplifier with Five Different Gains

## TRANSIMPEDANCE GAIN AMPLIFIER PERFORMANCE

Figure 62 shows the ADA4350 configured as a transimpedance amplifier with five different gains. The photodiode sensor capacitance,  $C_D$ , varies from 91 pF to 100 nF to showcase the transimpedance gain performance at various frequency. Figure 63 to Figure 66 shows the transimpedance vs. frequency at different  $C_D$  settings. Note that the compensation capacitors,  $C_{F0}$  to  $C_{F4}$ , correct for the inherent instability of the transimpedance configuration. Capacitors chosen were such that the transimpedance gain response compensates for the maximum bandwidth and is close to having a 45° phase margin.

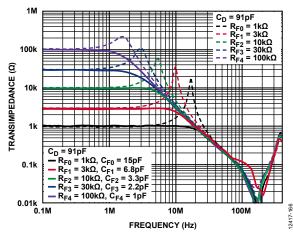
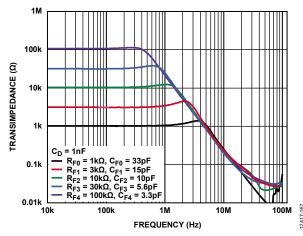


Figure 63. Transimpedance vs. Frequency,  $C_D = 91 \text{ pF}$ 



2417-065

Figure 64. Transimpedance vs. Frequency,  $C_D = 1$  nF

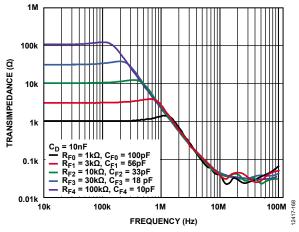


Figure 65. Transimpedance vs. Frequency,  $C_D = 10 \text{ nF}$ 

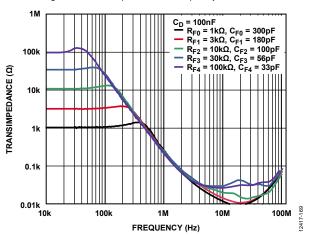


Figure 66. Transimpedance vs. Frequency,  $C_D = 100 \text{ nF}$ 

#### THE EFFECT OF LOW FEEDBACK RESISTOR RFX

As the load of the transimpedance amplifier increases, excessive peaking in the frequency response can be observed when the  $R_{\text{Fx}}$  value is too small. This peaking can persist even when excessive  $C_{\text{Fx}}$  is used to overcompensate for it. Figure 67 shows the ADA4350 configured with a photodiode capacitance value of 91 pF and a 1 k $\Omega$  transimpedance load. Figure 68 shows the normalized frequency response of this configuration. By decreasing  $R_{\text{F}}$  from 500  $\Omega$  to 68  $\Omega$ , the peaking in the frequency response increases progressively. The large peaking translates to a huge overshoot in the pulse response, which is an undesirable result.

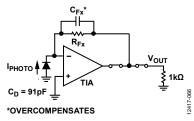


Figure 67. Transimpedance Amplifier Circuit

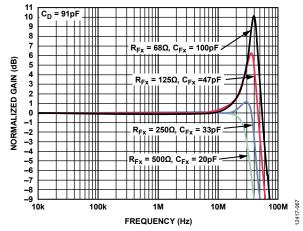


Figure 68. Normalized Frequency Response with Decreasing R<sub>F</sub> (See Figure 67)

To mitigate this effect, use an additional snubber circuit at the output of the FET input amplifier, as shown in Figure 69. In this configuration, the feedback resistor ( $R_{\text{Fx}}$ ) is 68  $\Omega$ , and the capacitance of the photodiode is 40 pF.

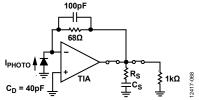


Figure 69. Snubber Circuit Added to Mitigate Peaking

Figure 70 shows the effect of various snubber circuits clamping down the peaking. Without the snubber circuit, there is 6 dB of peaking when an overcompensated  $C_{\text{Fx}}$  of 100 pF is used. With the snubber circuits, the bandwidth is restricted to approximately 10 MHz. To compromise between the peaking and the bandwidth, adjust the values of the snubber circuit.

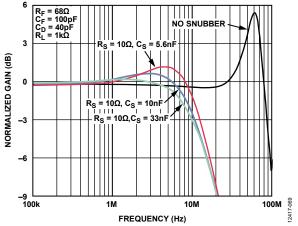


Figure 70. Effect of Snubber Circuits on the Transimpedance Frequency Response (See Figure 69)

## USING THE T NETWORK TO IMPLEMENT LARGE FEEDBACK RESISTOR VALUES

Large feedback resistors (>1 M $\Omega$ ) can cause the two following issues in the transimpedance amplifier design:

- If the parasitic capacitance of the feedback resistor exceeds the optimal compensation value, it can significantly reduce the TIA signal bandwidth.
- If the required compensation capacitance is too low (<1 pF), it is not practical to choose a feedback capacitor.</li>

The T network (the R<sub>Fx</sub>, R2, and R1 resistors) maintains the transimpedance gain and signal bandwidth with a lower feedback resistor and a resistive gain network, as shown in Figure 71.

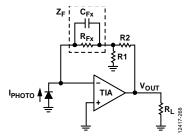


Figure 71. T Network

The relationship between the transimpedance  $V_{\text{OUT}}/I_{\text{PHOTO}}$  and the T network resistors ( $R_{\text{Fx}}$ , R1, and R2) can be expressed as

$$\frac{V_{OUT}}{I_{PHOTO}} = -Z_F \times \left(1 + \frac{R2}{R1} + \frac{R2}{Z_F}\right) \tag{10}$$

where:

 $V_{OUT}$  is the output voltage of the TIA.

*I*<sub>PHOTO</sub> is the input photodiode current.

 $Z_F = R_{Fx}/((R_{Fx} \times C_{Fx})s + 1)$ , where  $R_{Fx}$  and  $C_{Fx}$  are the feedback resistor and capacitor, respectively, of any of the chosen transimpedance gain paths.

R1 and R2 are the T network gain resistors.

If  $Z_F >> R2$ , the transimpedance equation is simplified to

$$\frac{V_{OUT}}{I_{PHOTO}} = -\frac{R_{F_x}}{(R_{F_x} \times C_{F_x})s + 1} \times \left(1 + \frac{R2}{R1}\right)$$

Therefore, as compared to the standard TIA design, the T network uses a feedback resistor value that is 1/(1+R1/R2) smaller to obtain the same transimpedance. This eliminates the concern of the high parasitic capacitance associated with the large feedback resistor. To maintain the same signal bandwidth (or same pole), increase  $C_F$  by a factor of 1+R2/R1 to eliminate concerns of an impractical small compensation capacitor.

As compared to a standard TIA design, the T network is noisier because the dominant voltage noise density is amplified by the gain factor 1 + R2/R1.

Figure 72 shows the ADA4350 configured as a 1  $M\Omega$  transimpedance path and its T network equivalent. Figure 73 compares the performance of the 1  $M\Omega$  path and the equivalent Tee network with and without compensation capacitors.

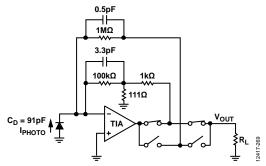


Figure 72. 1 M $\Omega$  Transimpedance Path and Its Equivalent T Network

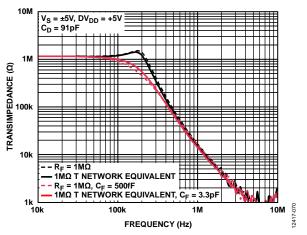
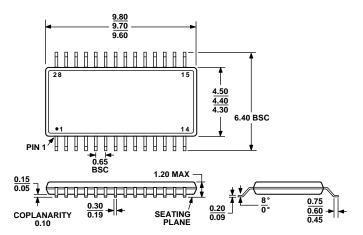


Figure 73. Comparing the 1 MΩ Transimpedance Path and T Network Performance

### **OUTLINE DIMENSIONS**



COMPLIANT TO JEDEC STANDARDS MO-153-AE

Figure 74. 28-Lead Thin Shrink Small Outline Package [TSSOP], (RU-28) Dimensions shown in millimeters

#### **ORDERING GUIDE**

| Model <sup>1</sup> | Temperature Range | Package Description  | Package Option |
|--------------------|-------------------|--|----------------|
| ADA4350ARUZ        | -40°C to +85°C    | 28-Lead Thin Shrink Small Outline Package [TSSOP]                      | RU-28          |
| ADA4350ARUZ-R7     | -40°C to +85°C    | 28-Lead Thin Shrink Small Outline Package [TSSOP]                      | RU-28          |
| EVAL-ADA4350RUZ-P  |                   | Evaluation Board for 28-Lead TSSOP, Precision Version with Guard Rings |                |

<sup>&</sup>lt;sup>1</sup> Z = RoHS Compliant Part.